

## STC04IE170HV

# Monolithic emitter switched bipolar transistor ESBT $^{\mbox{\tiny B}}$ 1700 V - 4 A - 0.17 $\Omega$

### Features

V <sub>CS(ON)</sub>	Ι <sub>C</sub>	R <sub>CS(ON)</sub>
0.7 V	4 A	0.17 Ω

- High voltage / high current cascode configuration
- Low equivalent ON resistance
- Very fast-switch: up to 150 kHz
- Squared RBSOA: up to 1700 V
- Very low  $C_{ISS}$  driven by  $R_G = 47 \Omega$
- Very low turn-off cross over time

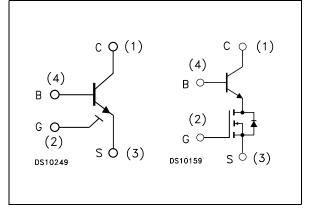
## Application

■ Aux SMPS for three-phase mains

## Description

The STC04IE170HV is manufactured in monolithic ESBT technology, aimed at providing the best performance in high frequency / high voltage applications. It is designed for use in gate driven based topologies. то247-4L HV

Figure 1. Internal schematic diagrams



#### Table 1. Device summary

Order code	Marking	Package	Packing
STC04IE170HV	C04IE170HV	TO247-4L HV	Tube

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## 1 Electrical ratings

Table 2.	Absolute	maximum	ratings
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Symbol	Parameter	Value	Unit
V <sub>CS(SS)</sub>	Collector-source voltage ( $V_{BS} = V_{GS} = 0$ )	1700	V
V <sub>BS(OS)</sub>	Base-source voltage ( $I_C = 0$ , $V_{GS} = 0$ )	30	V
V <sub>SB(OS)</sub>	Source-base voltage ( $I_C = 0$ , $V_{GS} = 0$ )	17	V
V <sub>GS</sub>	Gate-source voltage	± 17	V
۱ <sub>C</sub>	Collector current	4	А
I <sub>CM</sub>	Collector peak current ( $t_P < 5$ ms)	8	А
I <sub>B</sub>	Base current	4	Α
I <sub>BM</sub>	Base peak current (t <sub>P</sub> < 1 ms)	8	А
P <sub>tot</sub>	Total dissipation at $T_c \le 25 \text{ °C}$	178	W
T <sub>stg</sub>	Storage temperature	-40 to 150	°C
Т <sub>Ј</sub>	Max. operating junction temperature	150	°C

#### Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thJC</sub>	Thermal resistance junction-case	0.7	°C/W



## 2 Electrical characteristics

(T<sub>case</sub> = 25 °C unless otherwise specified)

Table 4.Electrical characteristics

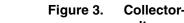
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CS(SS)</sub>	Collector cut-off current $(V_{BS} = V_{GS} = 0)$	V <sub>CS</sub> = 1700 V			100	μA
I <sub>BS(OS)</sub>	Base cut-off current ( $I_C = 0, V_{GS} = 0$ )	V <sub>BS</sub> = 30 V			10	μA
I <sub>SB(OS)</sub>	Source cut-off current $(I_C = 0, V_{GS} = 0)$	V <sub>SB</sub> = 17 V			100	μA
I <sub>GS(OS)</sub>	Gate-source leakage current (V <sub>BS</sub> = 0)	V <sub>GS</sub> = ± 17 V			100	nA
V <sub>CS(ON)</sub>	Collector-source ON voltage	$V_{GS} = 10 V I_C = 4 A I_B = 0.8 A$ $V_{GS} = 10 V I_C = 1.5 A I_B = 0.15 A$		0.7 0.6	1.5 1.4	V V
$h_{FE}^{(1)}$	DC current gain	$V_{CS} = 1 V V_{GS} = 10 V I_C = 4 A$ $V_{CS} = 1 V V_{GS} = 10 V I_C = 1.5 A$	4 7	5.5 11		
V <sub>BS(ON)</sub>	Base-source ON voltage			1.3 0.9	1.5 1.1	V V
V <sub>GS(th)</sub>	Gate threshold voltage	$V_{BS} = V_{GS}$ $I_B = 250 \ \mu A$	2	3	4	V
C <sub>iss</sub>	Input capacitance $(V_{GS} = V_{CB} = 0)$	V <sub>CS</sub> = 25 V f = 1 MHz		510		pF
Q <sub>GS(tot)</sub>	Gate-source charge (V <sub>CB</sub> = 0)	V <sub>GS</sub> = 10 V		3.9		nC
t <sub>s</sub> t <sub>f</sub>	Inductive load Storage time Fall time	$ \begin{array}{ll} V_{GS} = 10 \ V & R_G = 47 \ \Omega \\ V_{Clamp} = 1360 \ V & t_p = 4 \ \mu s \\ I_C = 2 \ A & I_B = 0.4 \ A \end{array} $		770 10		ns ns
t <sub>s</sub> t <sub>f</sub>	Inductive load Storage time Fall time			410 10		ns ns
V <sub>CS(dyn)</sub>	Collector-source dynamic voltage (0.5 µs)	$\begin{split} & V_{CC} = V_{Clamp} = 400 \; V \\ & V_{GS} = 10 \; V & I_C = 1.5 \; A \\ & I_B = 0.3 \; A & t_{peak} = 500 \; \text{ns} \\ & R_G = 47 \; \Omega & I_{Bpeak} = 3 \; A \; (2I_C) \end{split}$		5.36		V
V <sub>CS(dyn)</sub>	Collector-source dynamic voltage (1 µs)	$\begin{split} & V_{\text{CC}} = V_{\text{Clamp}} = 400 \; V \\ & V_{\text{GS}} = 10 \; V \qquad I_{\text{C}} = 1.5 \; A \\ & I_{\text{B}} = 0.3 \; A \qquad t_{\text{peak}} = 500 \; \text{ns} \\ & R_{\text{G}} = 47 \; \Omega \qquad I_{\text{Bpeak}} = 3 \; A \; (2I_{\text{C}} \; ) \end{split}$		4.32		V
V <sub>CSW</sub>	Maximum collector- source voltage at turn- off without snubber	$R_{G} = 47 \Omega$ $h_{FE} = 5$ $I_{C} = 4 A$	1700			V

1. Pulsed duration = 300  $\mu s,$  duty cycle  $\leq 1.5\%.$ 

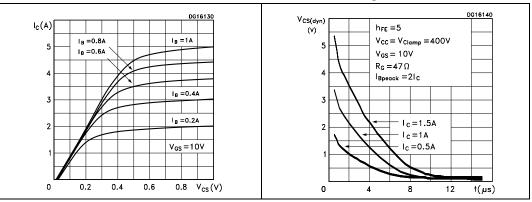


#### 2.1 **Electrical characteristics (curves)**

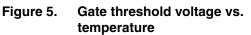


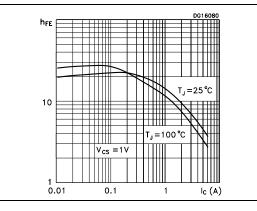


**Collector-source dynamic** voltage









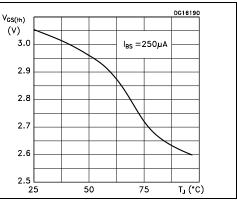
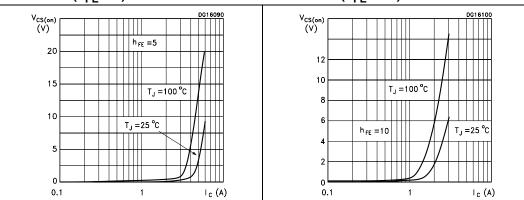
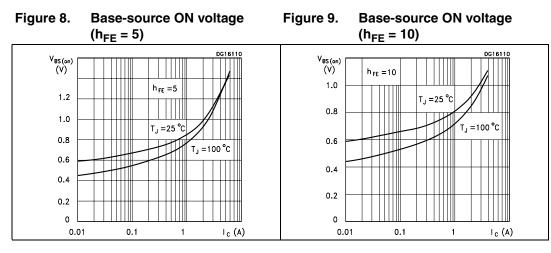
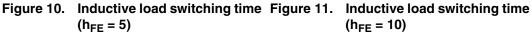


Figure 6. Collector-source ON voltage Figure 7.  $(h_{FE} = 5)$ 

**Collector-source ON voltage**  $(h_{FE} = 10)$ 







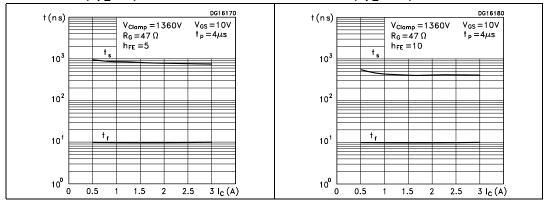
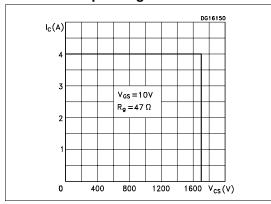


Figure 12. Reverse biased safe operating area



## **3** Package mechanical data

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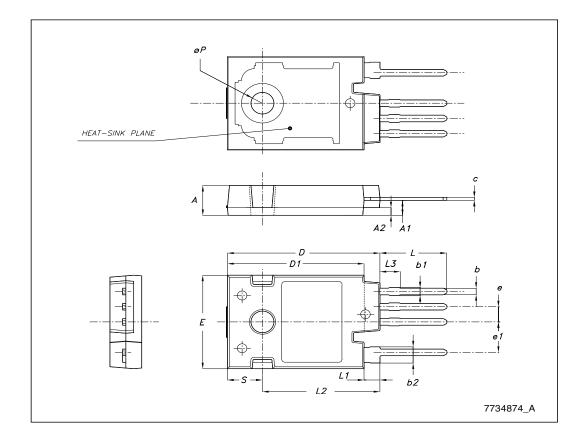


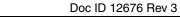
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DIM.		mm.	
	MIN.	ТҮР	MAX.
A	4.85		5.15
A1	2.20	2.50	2.60
A2		1.27	
b	0.95	1.10	1.30
b1	1.10		1.50
b2	2.50		2.90
С	0.40		0.80
D	23.85	24	24.15
D1		21.50	
E	15.45	15.60	15.75
е		2.54	
e1		5.08	
L	10.20		10.80
L1	2.20	2.50	2.80
L2		18.50	
L3		3	
øP	3.55		3.65
S		5.50	





## 4 Revision history

#### Table 5.Document revision history

Date	Revision	Changes
11-Sep-2006	1	First release.
21-Nov-2006	2	Improved application target.
16-Jun-2009	3	Updated Figure 2 on page 4 and mechanical data.



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